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SEMICONDUCTOR®

ISL9R860P2, ISL9R860S3ST

8 A, 600 V, STEALTH™ Diode

Features

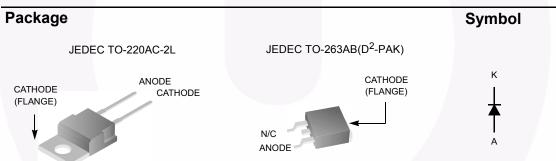
- Stealth Recovery t_{rr} = 28 ns (@ IF = 8 A)
- Max Forward Voltage, V_F = 2.4 V (@ T_C = 25° C)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

Applications

- SMPS FWD
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- Snubber Diode

Description

The ISL9R860P2, ISL9R860S3ST is a STEALTHTM diode optimized for low loss performance in high frequency hard switched applications. The STEALTHTM family exhibits low reverse recovery current (I_{RR}) and exceptionally soft recovery under typical operating conditions. This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RR} and short ta phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTHTM diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.



Device Maximum Ratings Tc= 25°C unless otherwise noted

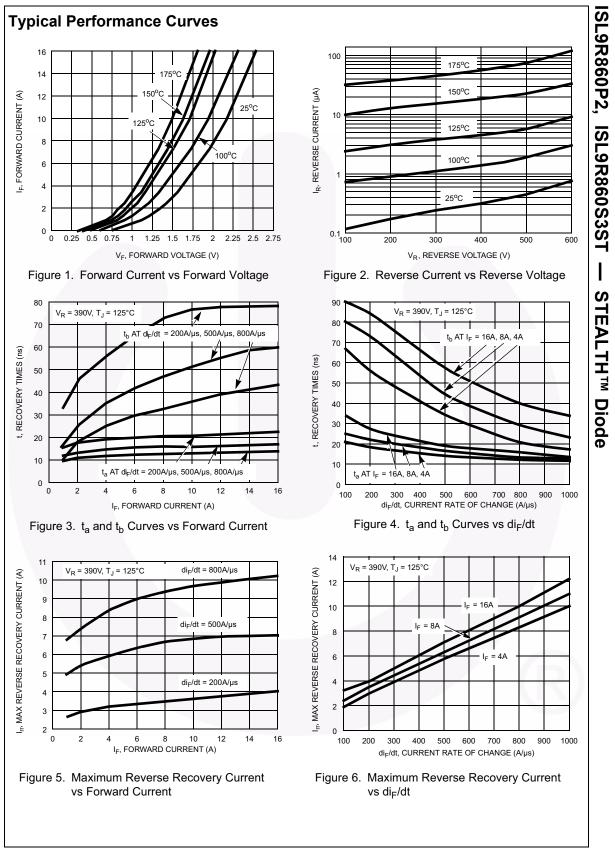
Symbol	Parameter	Ratings	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current (T _C = 147 ^o C)	8	Α	
I _{FRM}	Repetitive Peak Surge Current (20kHz Square Wave)	16	Α	
I _{FSM}	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	100	Α	
PD	Power Dissipation	85	W	
E _{AVL}	Avalanche Energy (1 A, 40 mH)	20	mJ	
J, T _{STG}	Operating and Storage Temperature Range	-55 to 175	°C	
T	Maximum Temperature for Soldering	300	°C	
Т _{РКG}	Leads at 0.063in (1.6mm) from Case for 10s Package Body for 10s, See Techbrief TB334	260	°C	

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August 2018

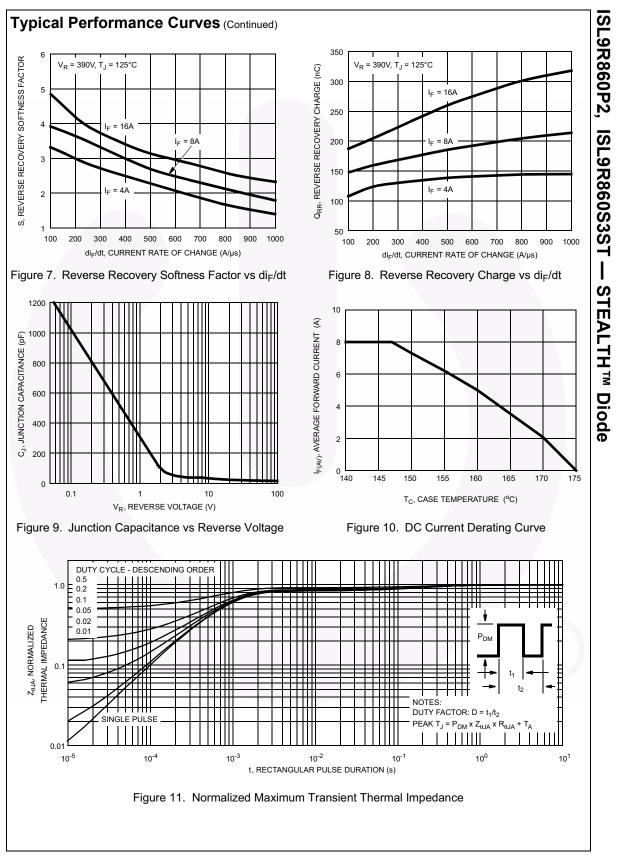
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eristics		0 A					
	i			-	30	-	pF
covery Time	1						
	I _F = 1 A, di _F /dt	= 100 A/µs	s, V _R = 30 V	-	18	25	ns
	I _F = 8 A, di _F /dt	= 100 A/µs	s, V _R = 30 V	-	21	30	ns
covery Time	I _F = 8 A,			-	28	-	ns
covery Current		$-1/_{-} = 390 \text{ //} T_{-} = 25^{\circ}\text{C}$		3.2	-	A	
covery Charge	-	- 20 0		-	50	-	nC
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ISI 9R860P2 ISI 9R860S3ST STEAI THTM Diode

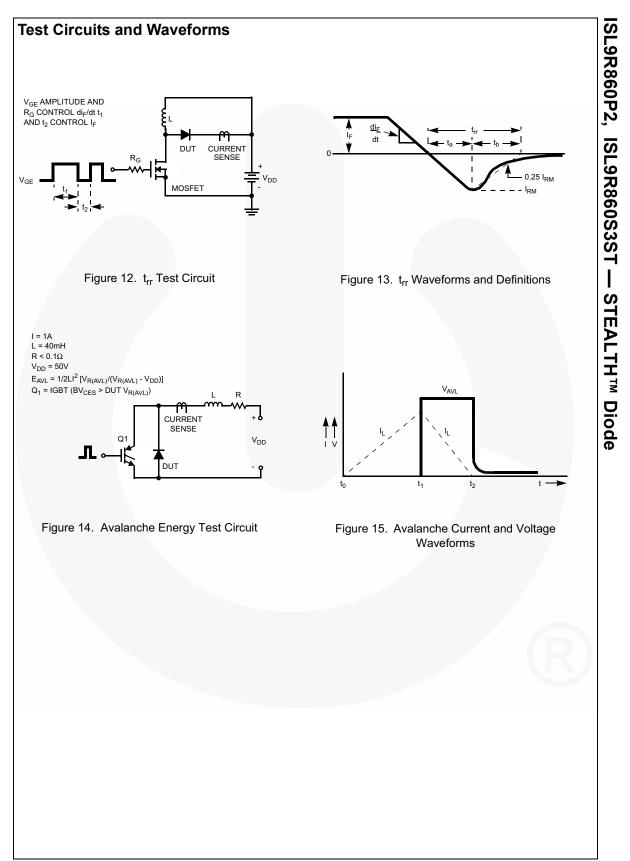


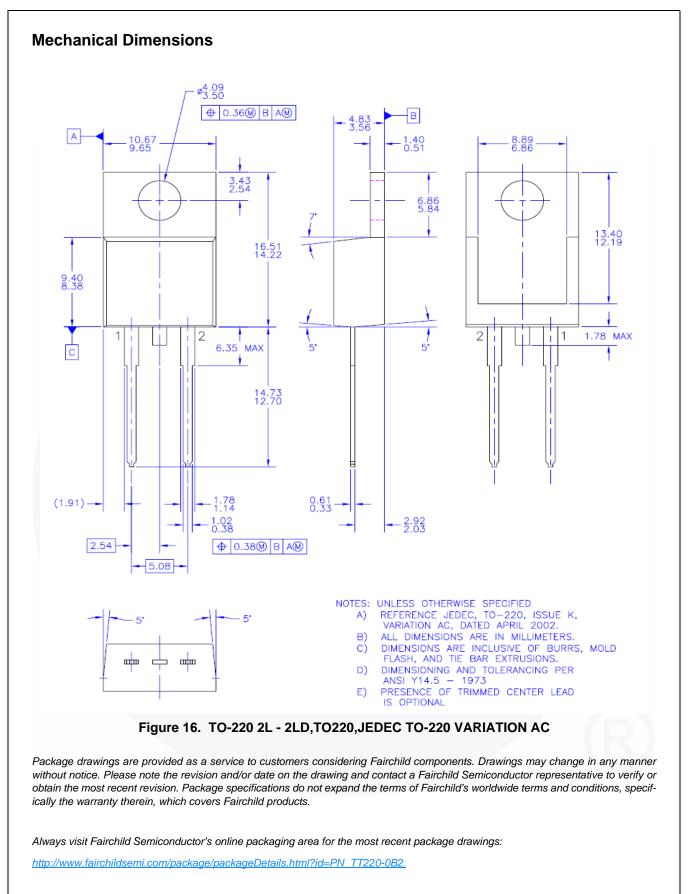
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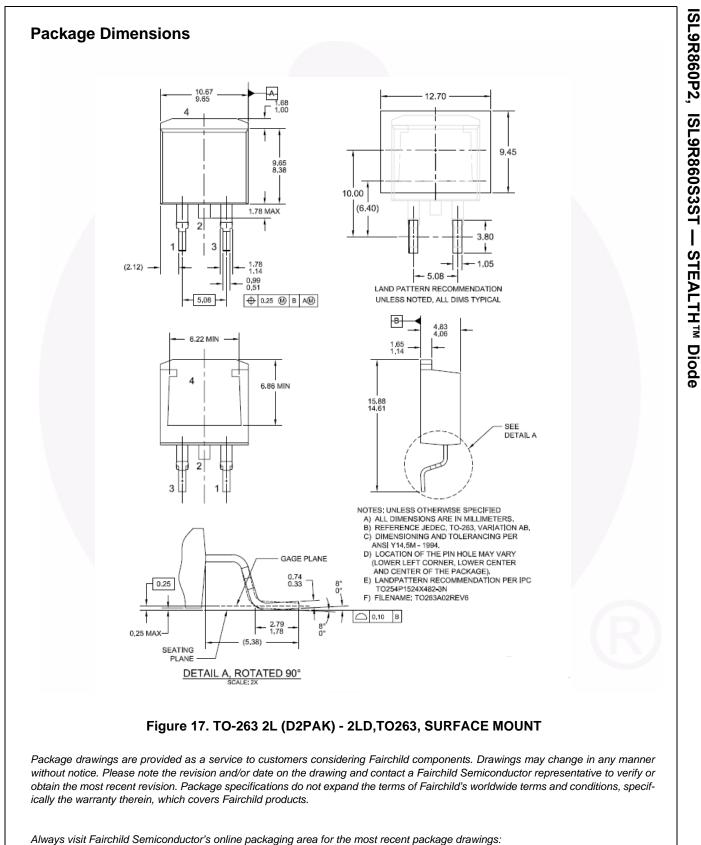
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